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## STPS5L40

### POWER SCHOTTKY RECTIFIER

### MAIN PRODUCT CHARACTERISTICS

IF(AV)	5 A		
V <sub>RRM</sub>	40 V		
Tj (max)	150°C		
V <sub>F</sub> (max)	0.44 V		

### FEATURES AND BENEFITS

- Negligible switching losses
- . Low forward voltage drop for higher efficiency.
- Low thermal resistance

### DESCRIPTION

Axial Power Schottky rectifier suited for Switch Mode Power Supplies and high frequency inverters.

Packaged in DO-201AD, this device is intended for use in low voltage output for small battery chargers & consumer SMPS such as DVD and Set-Top-Box..

### ABSOLUTE RATINGS (limiting values)

Paramete	Value	Unit	
Repetitive peak reverse voltage		40	V
RMS forward current		15	A
Average forward current	TI = 100°C δ = 0.5	5	А
Surge non repetitive forward current	Half wave, single phase tp = 10 ms	150	A
Storage temperature range		- 65 to + 150	°C
Maximum operating junction temperature *		150	°C
Critical rate of rise of reverse voltage (rated $V_R$ , Tj = 25°C)		10000	V/µs
	Repetitive peak reverse voltage RMS forward current Average forward current Surge non repetitive forward current Storage temperature range Maximum operating junction temperatu	RMS forward currentTI = $100^{\circ}C$ $\delta = 0.5$ Average forward currentTI = $100^{\circ}C$ $\delta = 0.5$ Surge non repetitive forward currentHalf wave, single phase tp = $10$ msStorage temperature rangeMaximum operating junction temperature *	Repetitive peak reverse voltage40RMS forward current15Average forward currentTI = 100°C $\delta$ = 0.55Surge non repetitive forward currentHalf wave, single phase tp = 10 ms150Storage temperature range- 65 to + 150Maximum operating junction temperature *150

 $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$  thermal runaway condition for a diode on its own heatsink



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#### THERMAL PARAMETERS

Symbol	Parameter		Value	Unit
R <sub>th(j-a)</sub>	Junction to ambient		75	°C/W
Rth(J-I)	Junction to leads	Lead length = 10 mm	15	°C/W

### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> *	Reverse leakage current	Tj = 25°C	V <sub>R</sub> = V <sub>RRM</sub>			0.2	mA
	-	Ti = 100°C	7		8	25	
		Tj = 125°C			25	75	
V <sub>F</sub> * Forward voltage drop	Ti = 25°C	$I_F = 5 A$		0.44	0.50	V	
	Ti = 100°C			0.40	0.46		
		Tj = 125°C			0.38	0.44	

IF(av)(A)

δ≃te

25

6

3

2

0

0

Pulse test : \* tp = 380  $\mu$ s,  $\delta$  < 2%

To evaluate the maximum conduction losses use the following equation:

 $P = 0.34 \times I_{F(AV)} + 0.028 \times I_{F}^{2}(RMS)$ 

Fig. 1: Conduction losses versus average current.



Rthli

50



Fig. 3: Non repetitive surge peak forward current versus overload duration (maximum values).



**Fig. 4:** Relative variation of thermal impedance junction to ambient versus pulse duration.

Tamb(°C)

75

100

125

150



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# PACKAGE MECHANICAL DATA DO-201AD plastic

